

First-Principles Modeling of Hydrogen Storage in Metal Hydride Systems

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Project ID # STP3

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Carnegie Mellon

Overview

Timeline

- Project start date: FY05
- Project end date: FY10
- Percent complete: 20%

Budget

- Requested total: \$1.38M
- Cost sharing: 20%
- FY06 \$175k (DOE), \$44k (cost share)

Barriers

- Access to adequate computing resources
- Efficient and accurate electronic structure algorithms

Partners

- Collaborations with all experimental groups are sought
- Current collaborators:
 - HRL, GE, U. Hawaii, Stanford, UIUC, U. Utah, NIST, JPL, Cal Tech

Objectives

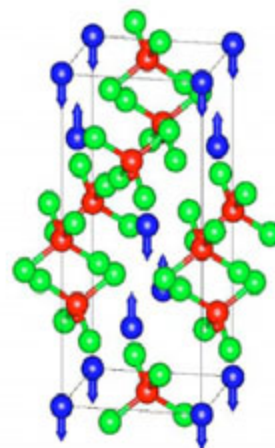
- Compute thermodynamic properties of metal hydride alloys—Heat of reaction, ΔH
 - Compute ΔH for known reactions to test accuracy of our approach
 - Compute ΔH for new reactions to identify promising destabilized compounds
 - This work complements experimental work on identifying destabilized metal hydrides (Focus area A—Destabilized Hydrides)
- Compute interfacial properties of hydrides
 - Metal-hydride interfaces
 - Surface energies of metal hydrides for nanoscopic hydrides
 - Apply principles learned on model systems to more promising novel materials.
 - Complements experimental work on improving kinetics for destabilized hydrides and other materials

Objectives

- Fundamental processes in hydrogenation
 - Study hydrogenation in destabilized hydrides and other systems to assess reversibility
 - Look for common hydrogenation pathways that might be applicable to other materials
 - Assess the role of interfacial transport
 - Some destabilized hydrides are not easily hydrogenated—this work supports experimental efforts to design a practical destabilized hydride system

Approach

- First principles density functional theory (DFT) for periodic systems (plane wave)
- Generalized gradient approximation (GGA) for the exchange-correlation functional
- Finite temperature and entropic properties computed from a phonon density of states approach with the PHONON software package
- Transition state finding methods for reaction and diffusion problems



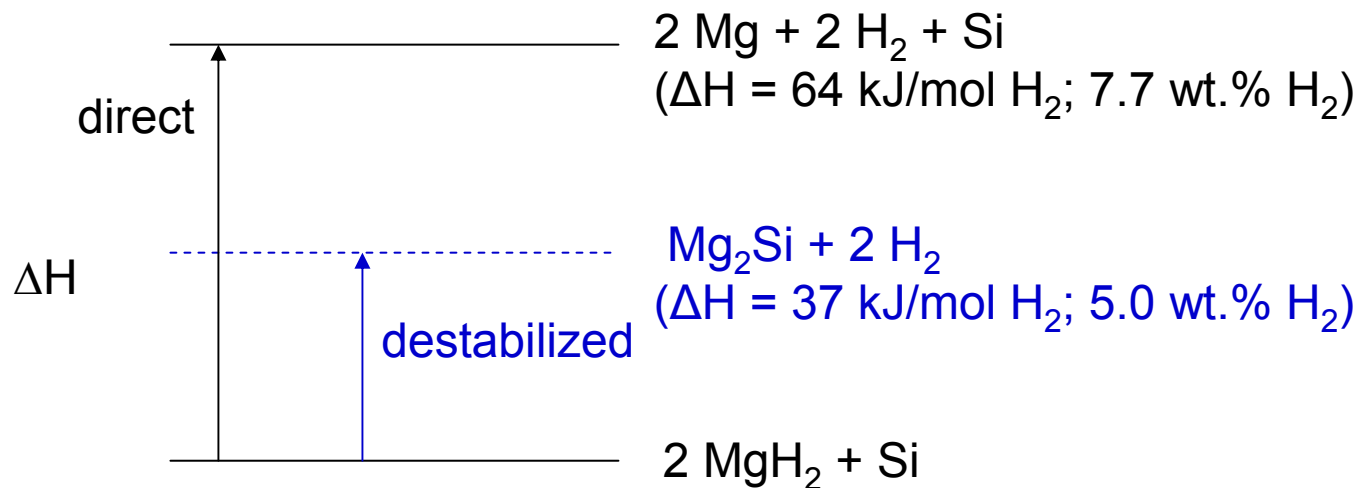
Destabilization of Metal Hydrides

Original concept introduced by Reilly and Wiswall¹ in late 1960's for Ni hydrides

Modification of dehydrogenation thermodynamics using additives

- Stabilized dehydrogenated state reduces enthalpy of dehydrogenation

Recent application of this concept to light metal hydrides by Vajo et al.^{2,3}



Technical Accomplishments

A DFT-based Database of Reaction Enthalpies

We have optimized the crystal structures of 52 solid materials listed in Wyckoff¹, Pearson² and ICSD³ comprised of Al, B, Ca, Li, Mg, Si, C, N, or H

Using this DFT-based database, we have considered 130 reactions that could not previously be evaluated as potential H₂ storage schemes.

1. R. W. G. Wyckoff, *The Structure of Crystals*, The Chemical Catalog Company Inc., New York, 1931.
2. P. Villars, *Pearson's handbook : crystallographic data for intermetallic phases*; Desk ed. ed.; ASM International
3. The Inorganic Crystal Structure Database (ICSD), <http://www.fiz-informationsdienste.de/en/DB/icsd/>.

Technical Accomplishments

A DFT-based Database of Reaction Enthalpies Crystal Structure Issues:

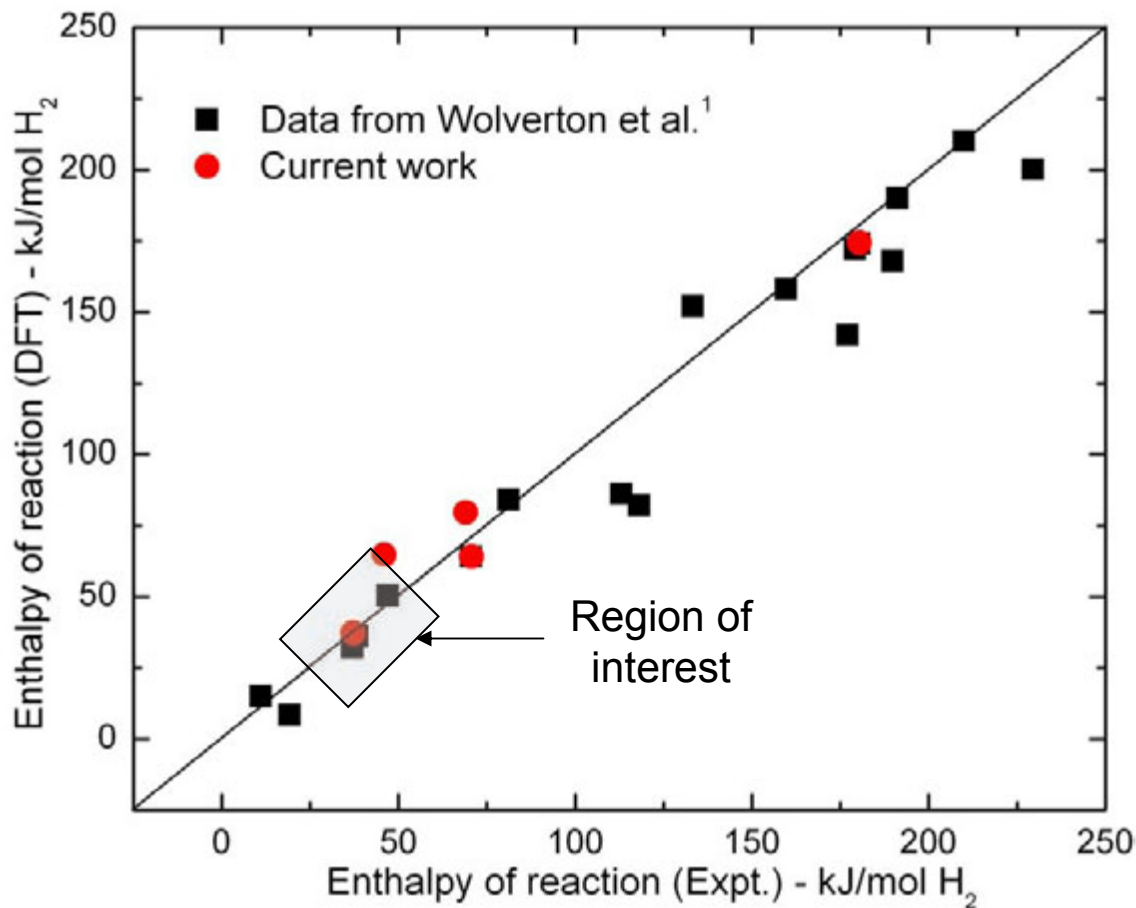
Full crystal structure of $\text{Ca}(\text{AlH}_4)_2$ is not known experimentally.
We used *ab initio* prediction of Løvvik¹

$\text{Li}_5\text{N}_3\text{Si}$ has very large unit cell with partial atomic occupancies.
DFT calculations performed with two materials with compositions
 $\text{Li}_{54}\text{N}_{32}\text{Si}_{10}$ and $\text{Li}_{53}\text{N}_{32}\text{Si}_{11}$ with Si distributed randomly.

1. O. M. Løvvik, *Phys. Rev. B* **2005**, 71, 144111

Accuracy of DFT - based Values of ΔH

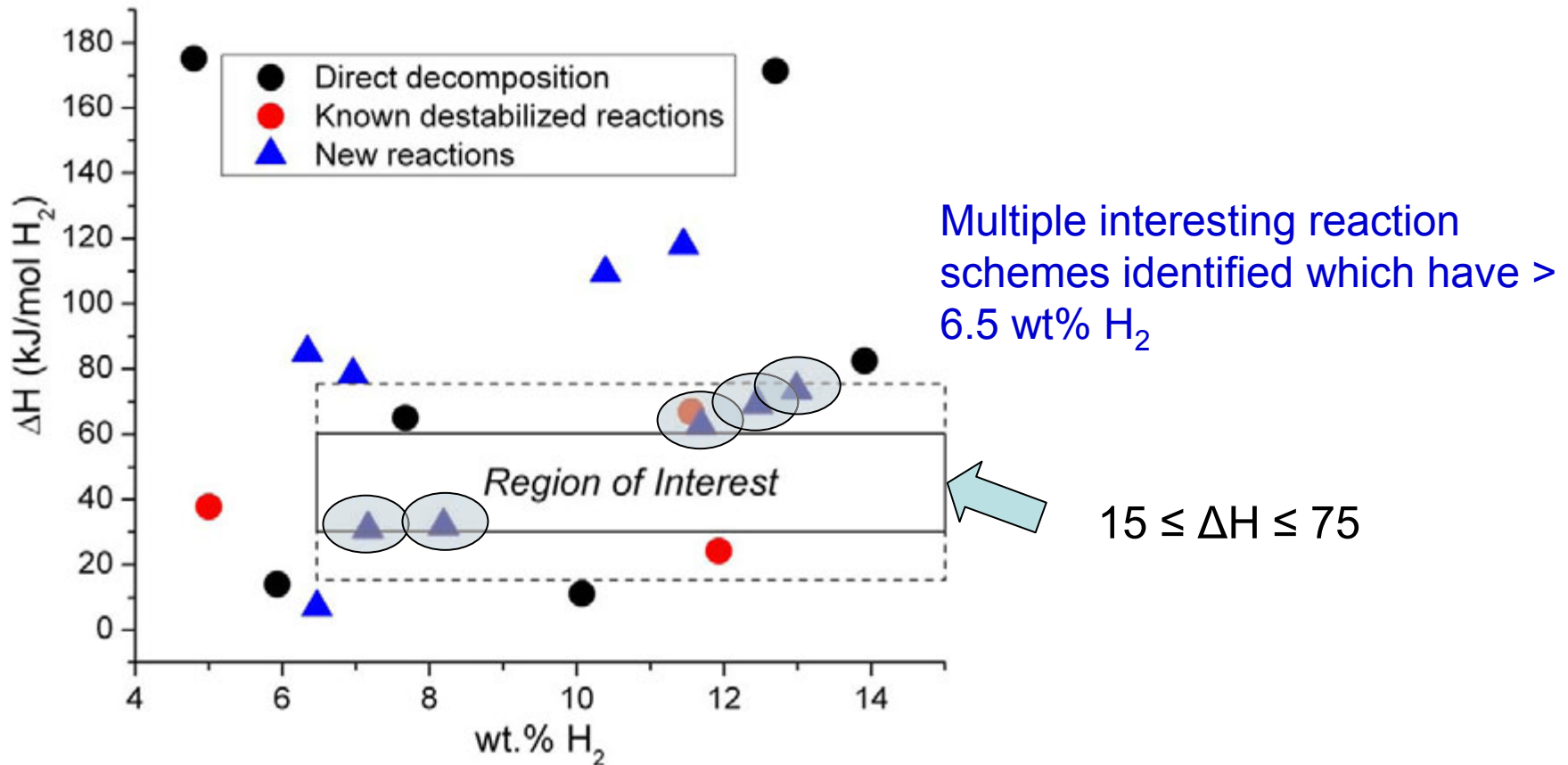
Experimental data available for many high Z metal hydrides (e.g. Sc, Pd, Ni, etc.)



RMS deviation in DFT results is 15 kJ/mol H₂ ;
this is sufficiently accurate for screening purposes

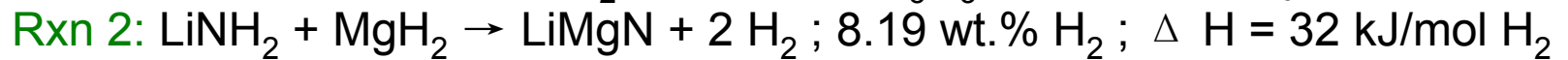
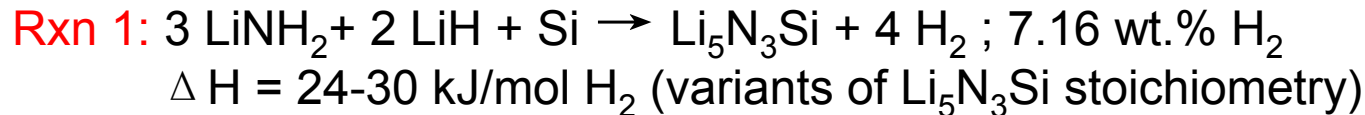
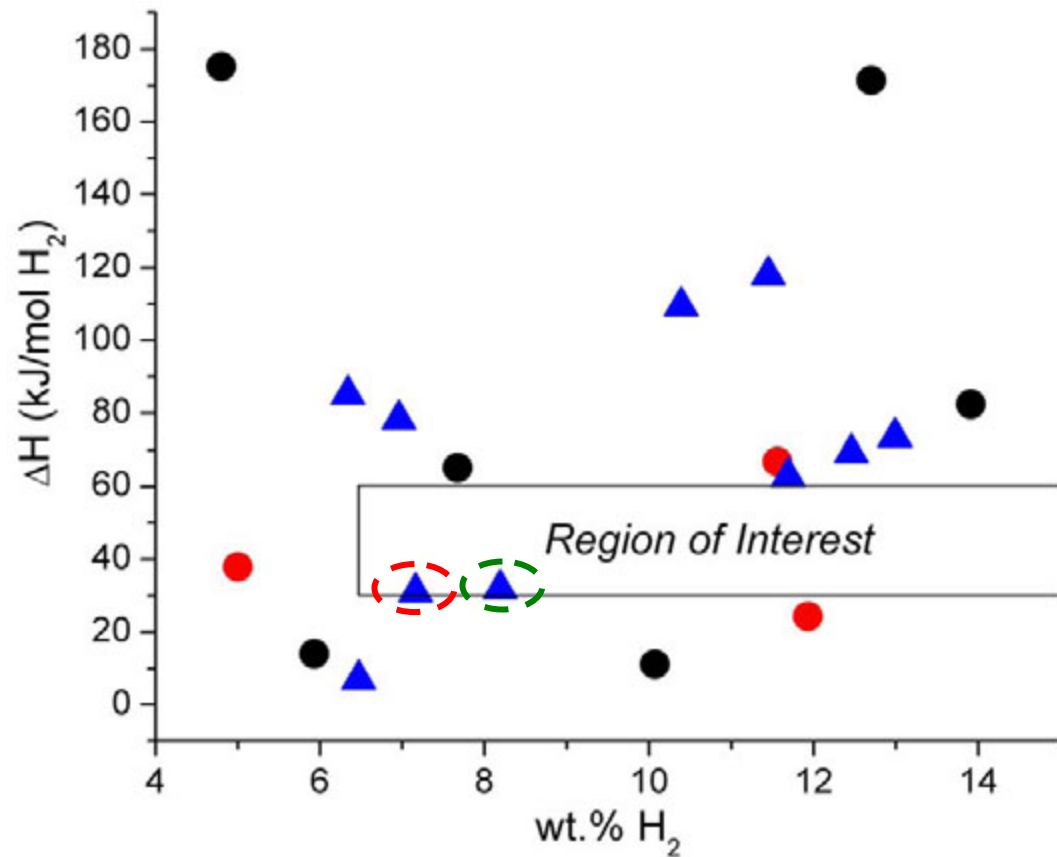
1. Wolverton et al., *Phys. Rev. B* **2004**, 69, 144109

Reactions of Interest

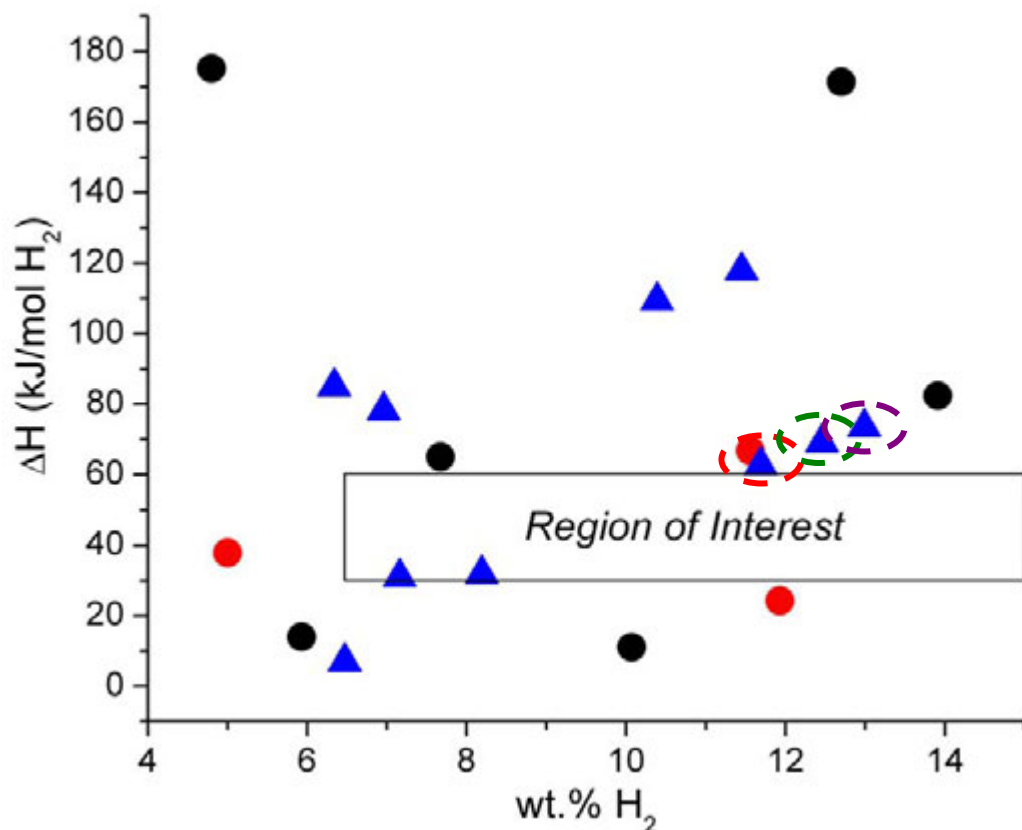


- Five new promising destabilization schemes identified – all have high storage densities and have promising thermodynamics.
- A large number of schemes (not shown) are less promising for either storage density or thermodynamic reasons (or both).

Reactions of Interest (cont.)



Reactions of Interest (cont.)

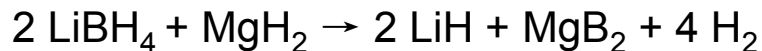


Rxn 3: $6 \text{LiBH}_4 + \text{CaH}_2 \rightarrow 6 \text{LiH} + \text{CaB}_6 + 10 \text{H}_2$; 11.7 wt.% H_2 ; $\Delta H = 62 \text{ kJ/mol H}_2$

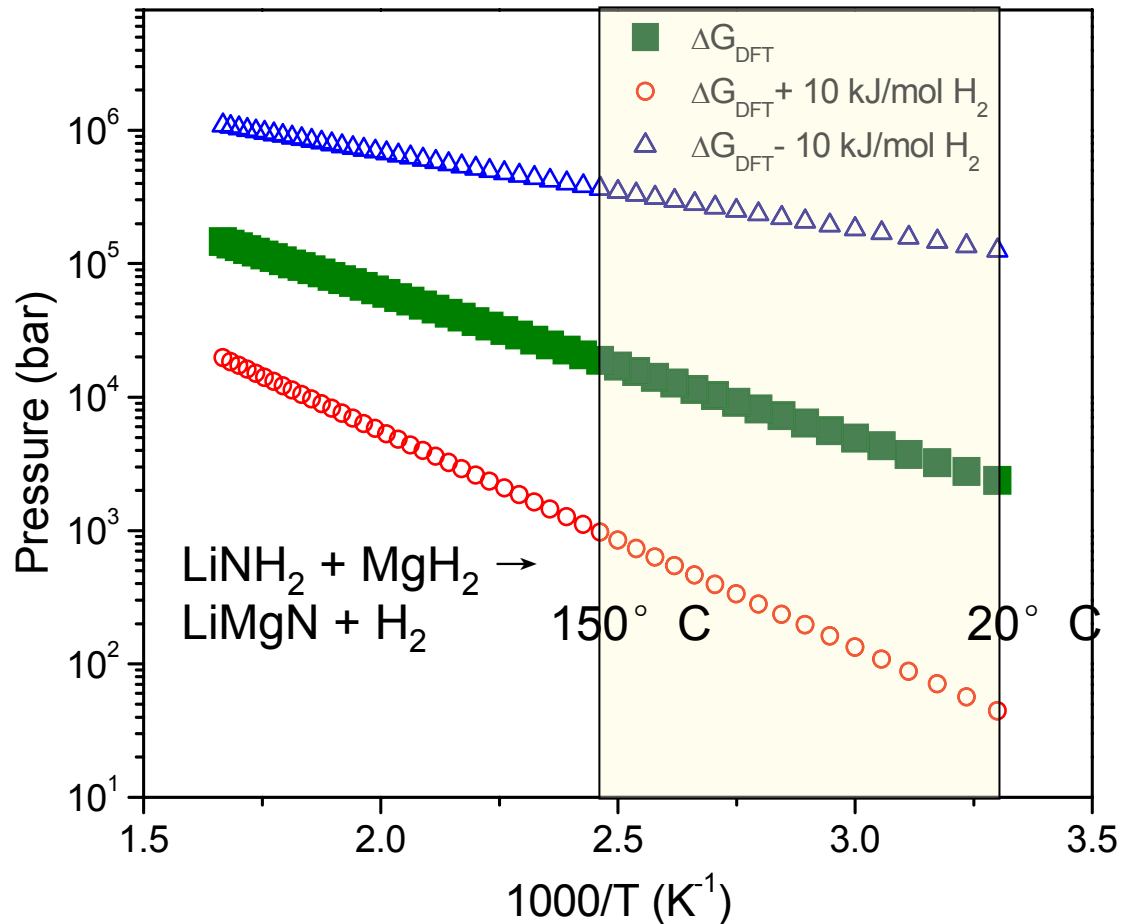
Rxn 4: $4 \text{LiBH}_4 + \text{MgH}_2 \rightarrow 4 \text{LiH} + \text{MgB}_4 + 7 \text{H}_2$; 12.5 wt.% H_2 ; $\Delta H = 69 \text{ kJ/mol H}_2$

Rxn 5: $7 \text{LiBH}_4 + \text{MgH}_2 \rightarrow 7 \text{LiH} + \text{MgB}_7 + 11.5 \text{H}_2$; 13.0 wt.% H_2 ; $\Delta H = 75 \text{ kJ/mol H}_2$

Rxn 4 and 5 analogous to Vajo et al.¹ reaction:



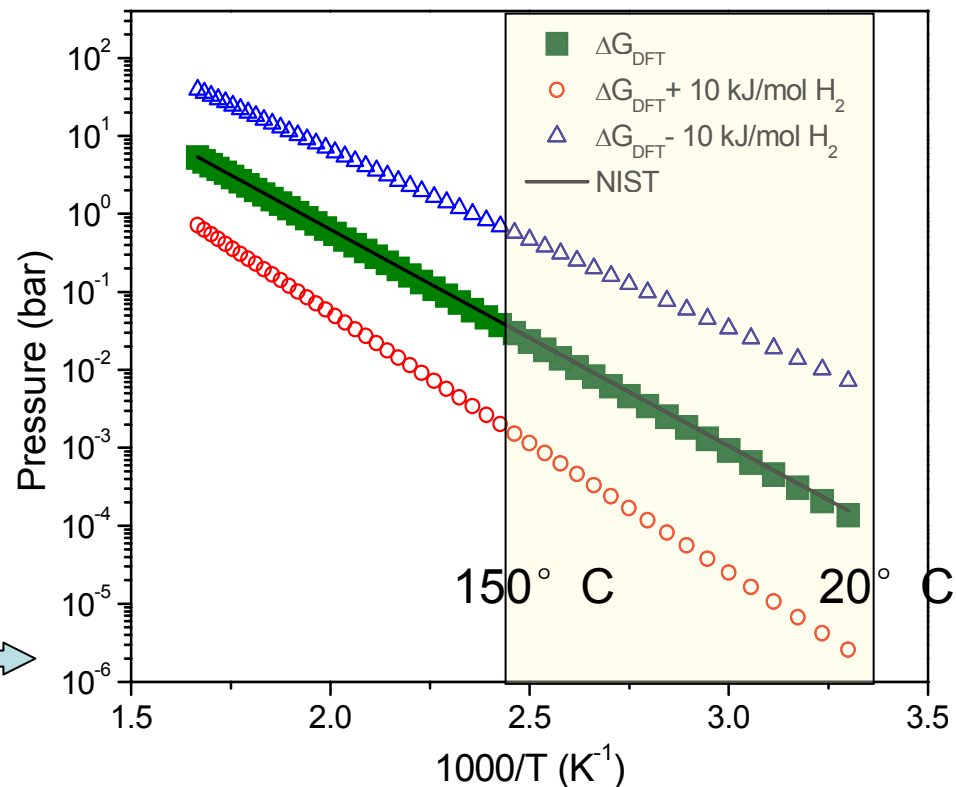
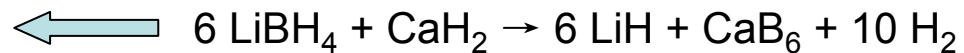
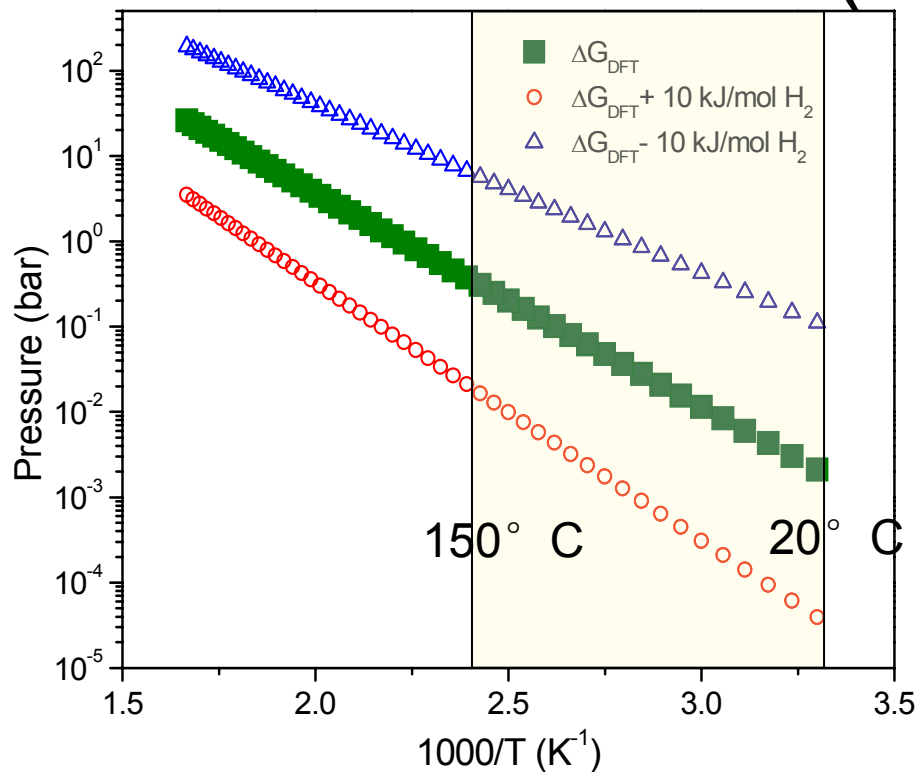
Van't Hoff Plots for New Reactions



- The equilibrium pressure is very high over the temperature range of interest
- May be a useful material at lower temperatures
- $\Delta H \sim 20 \text{ kJ/mol H}_2$ over the temperature range

Caveat: Reversibility might be an issue as ΔH is low

Van't Hoff Plots for New Reactions (cont.)



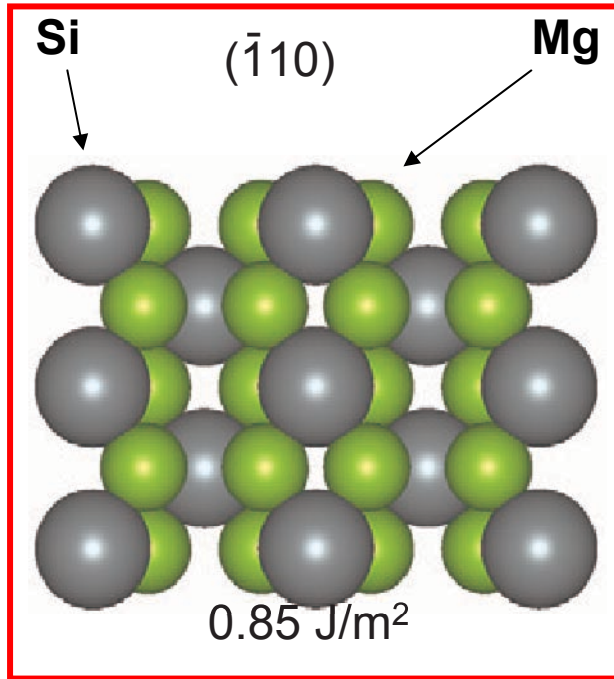
- Both these reactions have $P_{\text{eq}} < 1 \text{ bar}$ at room temperature
- The equilibrium pressure would need to be increased for these reactions to be useful

Computational Study of Dissociation of Hydrogen on Mg₂Si Surface

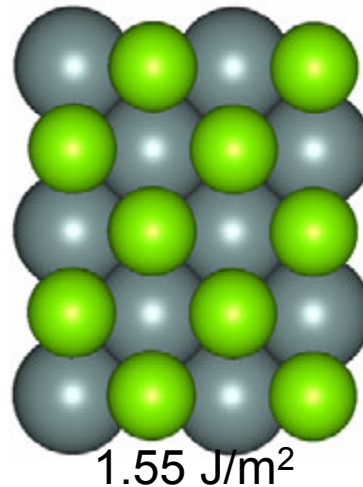
- One possible kinetic barrier to $\text{Mg}_2\text{Si} + \text{H}_2 \rightarrow \text{MgH}_2 + \text{Si}$ is the dissociation of H_2 on surfaces of Mg_2Si .
[Large barriers to H_2 dissociation are known to exist on $\text{Mg}(0001)$ ¹]
- This hypothesis can be disproved if facile pathways for H_2 dissociation are identified
- Many other atomic-scale processes must still be considered before a complete description of the overall hydrogenation reaction is available, i.e. oxide overlayer formation

Mg₂Si Surface Energies

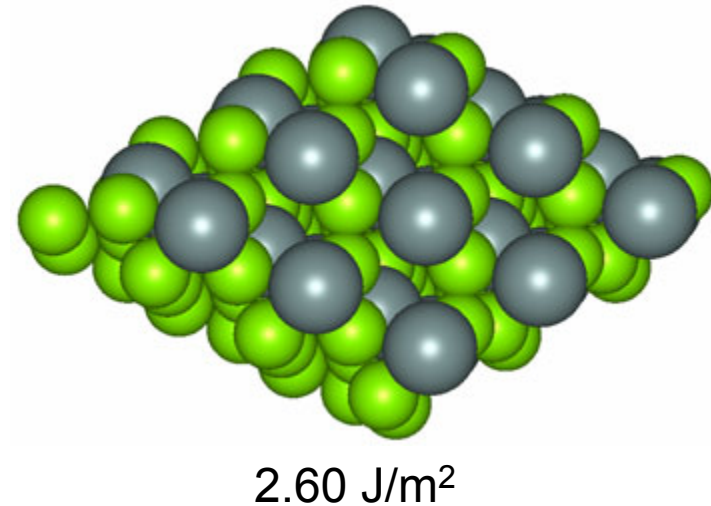
Surface energy is defined as: $E_{\text{surface}} = (E_{\text{total}} - N \times E_{\text{bulk}})/2A$



(110) ⇔ (101)



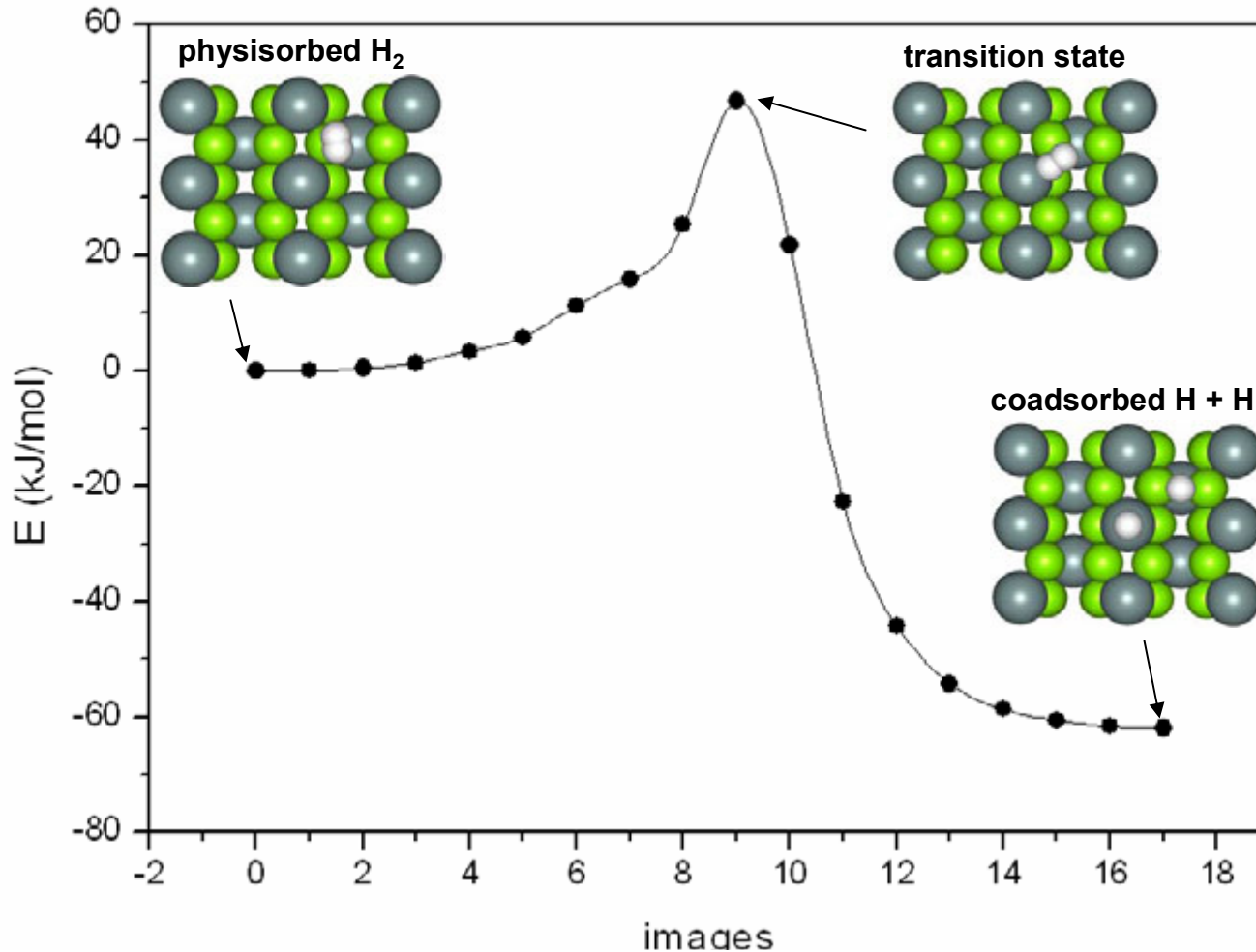
(111) ⇔ (100) ⇔ (010) ⇔ (001)



Lower surface energies correspond to more energetically stable surfaces

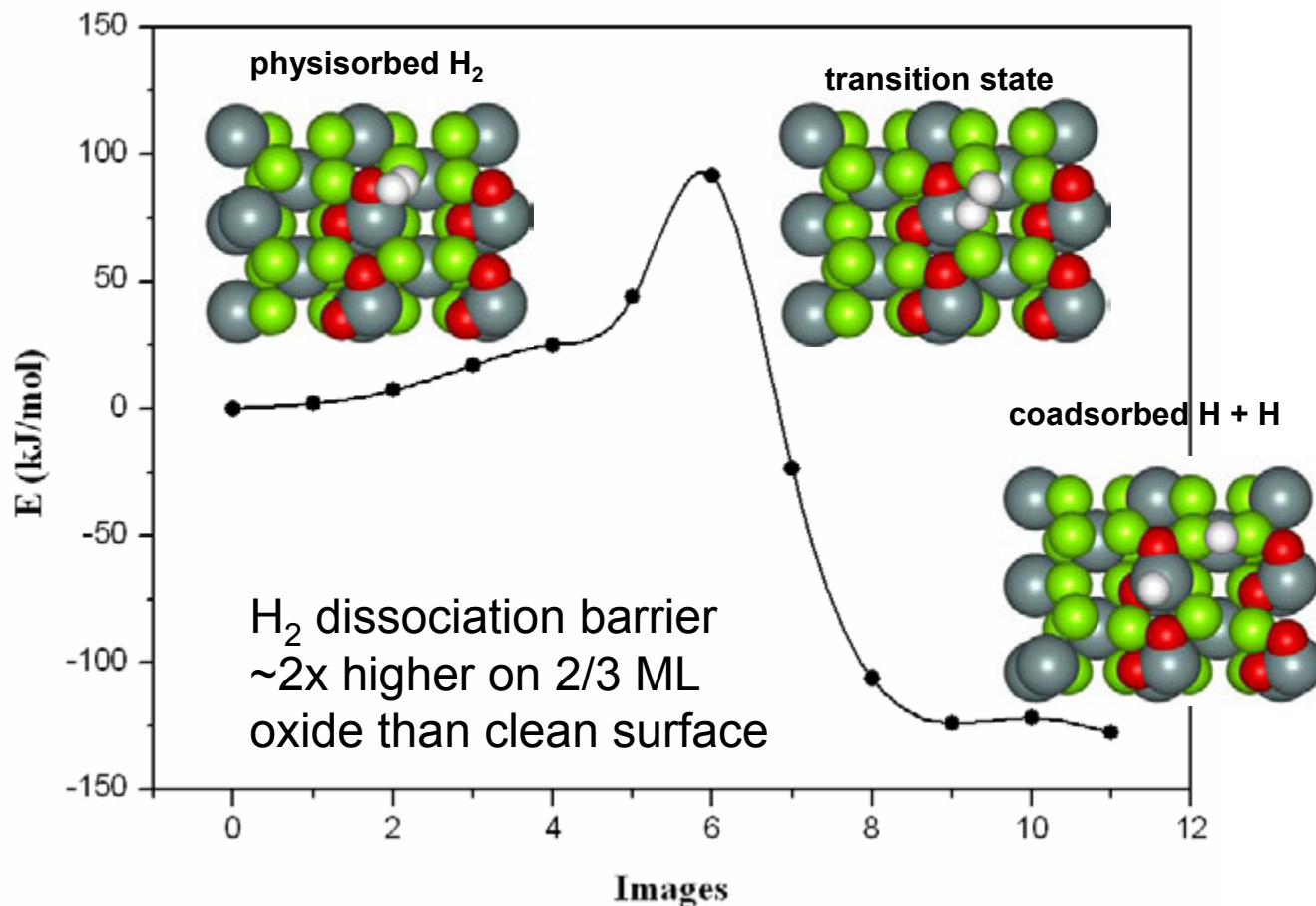
H₂ Dissociation on Mg₂Si($\bar{1}10$)

Pathway for H₂ dissociation determined using Nudged Elastic Band method



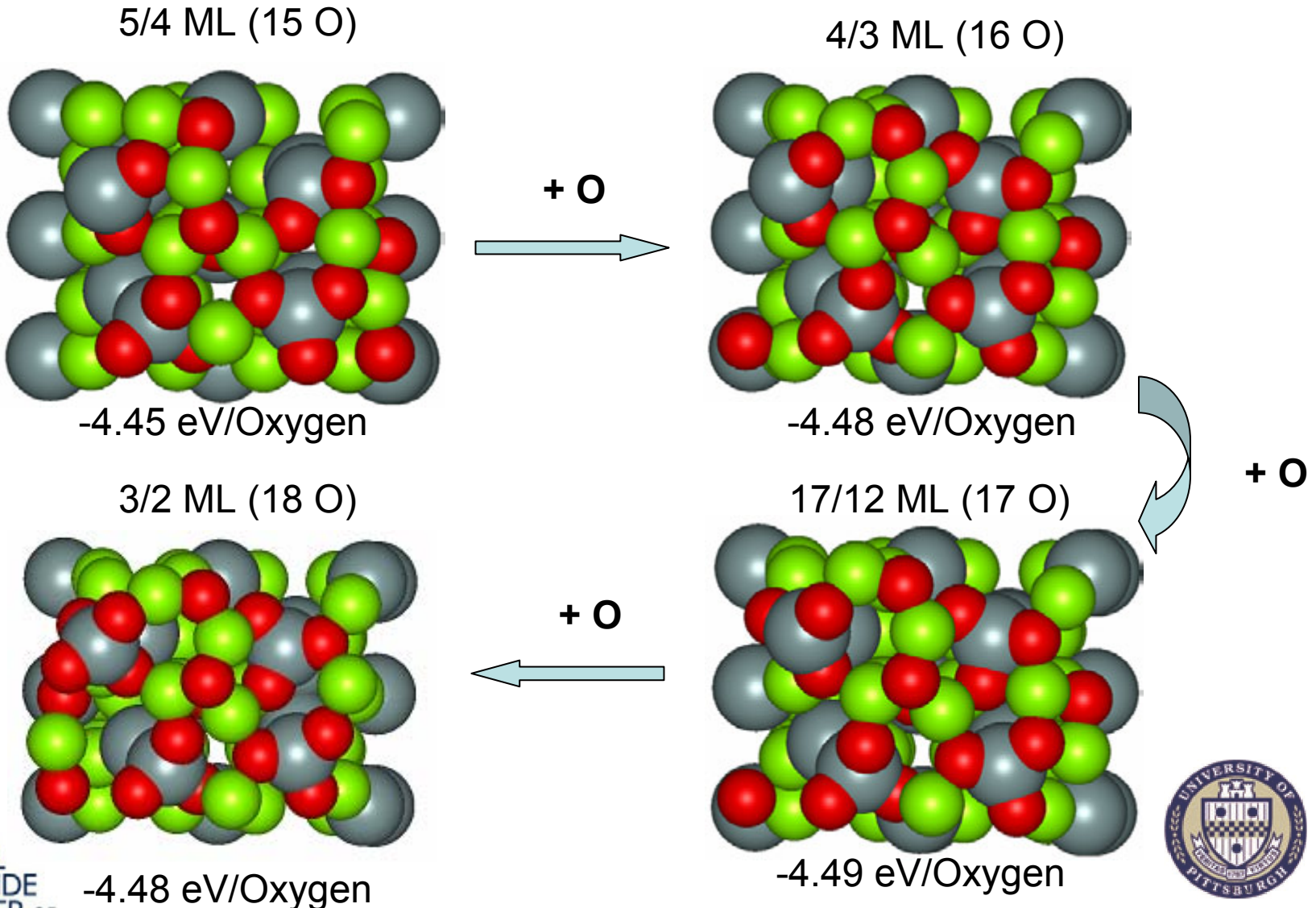
**Energy barrier to H₂ dissociation is 47 kJ/mol
(39 kJ/mol after zero point vibrational energy corrections)**

H₂ dissociation on 2/3 ML Oxidation Mg₂Si Surface



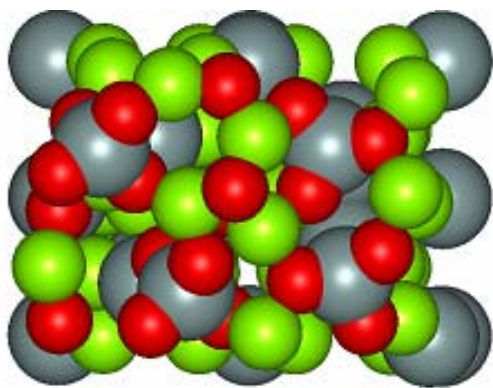
**Energy barrier to H₂ dissociation is 92 kJ/mol
(80 kJ/mol after zero point energy corrections)**

Mg₂Si Surface Oxide Formation (beyond 7/6 ML)



Mg₂Si Surface Oxide Formation (beyond 7/6 ML)

19/12 ML (19 O)

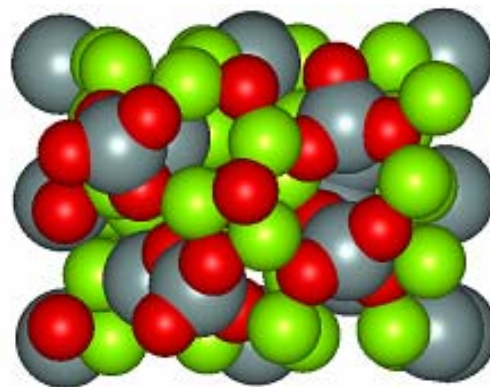


-4.45 eV/Oxygen

+ O

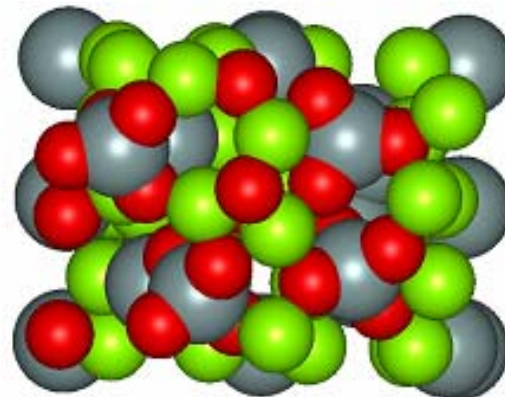


5/3 ML (20 O)



-4.49 eV/Oxygen

7/4 ML (21 O)

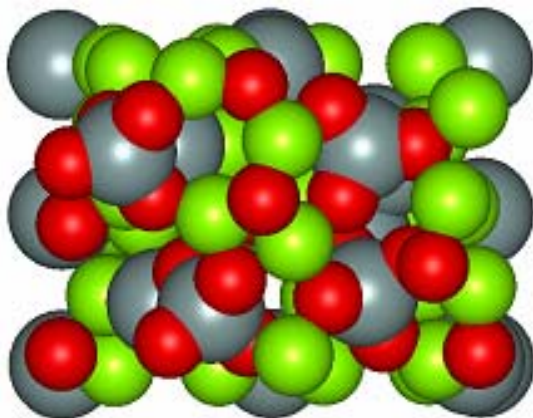


-4.45 eV/Oxygen

+ O



11/6 ML (22 O)



-4.22 eV/Oxygen



+ O

H₂ Dissociation on Oxide Mg₂Si Surface

- The adsorption energy per O atom is roughly constant from 1 ML to 7/4 ML, ~-4.5 eV

Coverage (ML)	1/3	2/3	1	13/12	7/6	5/4	4/3	17/12
E _{ads/O} (eV)	-3.57	-4.01	-4.44	-4.48	-4.45	-4.45	-4.48	-4.49
E _{ads/H} (eV)	----	-0.84	-0.53	-1.21	-0.23	----	----	----
Coverage (ML)	3/2	19/12	5/3	7/4	11/6			
E _{ads/O} (eV)	-4.48	-4.45	-4.49	-4.45	-4.22			

Future Work

- Continue work on destabilized hydride reversibility
- Investigate new reaction schemes for destabilized hydrides including other light elements
- Continue work on computing P-T diagrams for metal hydrides
- Continue work on interfacial energies
- Contribute data to the UIUC toolbox data base
- Collaborate with Ursula Kattner, NIST by computing thermodynamic properties of Li_5B_4 and other materials

Summary

- We have screened over one hundred destabilization reactions based on reaction enthalpy using DFT calculations
- Five promising reaction schemes have been identified
- Equilibrium pressures have been predicted for three of the reactions from first principles
- Facile dissociation of H_2 should be observed on the clean Mg_2Si surface
- Oxide formation on Mg_2Si is highly exothermic
- Hydrogen dissociation is inhibited on the oxidized Mg_2Si surface
- Our calculations are consistent with the experimental observation that ball milling in a hydrogen atmosphere is required for hydrogenation of Mg_2Si

Publications and Presentations

■ Publications:

- Identification of Destabilized Metal Hydrides for Hydrogen Storage Using First Principles Calculations, by S.V. Alapati, J.K. Johnson, D.S. Sholl, *J. Chem. Phys. B*, in press

■ Presentations:

- Invited talk at the “Hydrogen Storage with Novel Nanomaterials” workshop, 23-28 October, in Ban Honnef, Germany
- “Mechanisms of Hydrogen Adsorption in Metal Organic Frameworks”, AIChE Annual Meeting, Cincinnati, Ohio, 31 October to 4 November, 2005.
- J. Karl Johnson, Sudhakar V. Alapati, Bing Dai, David S. Sholl “Computational Study of Metal Hydride Destabilization” *American Physical Society March Meeting*, Baltimore, MD, 13-17 March, 2006.
- Bing Dai, Sudhakar V. Alapati, David S. Sholl and J. Karl. Johnson “First Principles Investigation of Adsorption and Dissociation of Hydrogen on the Mg₂Si Surface” 231st *American Chemical Society National Meeting*, Atlanta Georgia, 26-30 March 2006.
- Sudhakar V. Alapati, Bing Dai, J. Karl. Johnson and David S. Sholl, “First Principles Calculations of Destabilized Alloys for Hydrogen Storage Applications” *2006 TMS Annual Meeting*, San Antonio, TX, 12-16 March, 2006.
- Organized a session on “Nanotechnology related to the hydrogen economy” as part of the Nanotechnology and the Environment symposium, ACS National Meeting, Atlanta, GA, 26-30 2006